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[54] **INTEGRATED QUANTUM WELL LASERS FOR WAVELENGTH DIVISION MULTIPLEXING**

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Related U.S. Application Data

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[52] **U.S. Cl.** ..... **29/569 L**; 29/576 E; 148/175; 148/DIG. 66; 148/DIG. 95; 148/DIG. 72

[58] **Field of Search** ..... 29/569 L, 576 E; 357/17; 372/46, 47, 48, 50; 148/DIG. 65, DIG. 66, DIG. 72, DIG. 95, 174, 175; 727/38

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[57] **ABSTRACT**

An integrated quantum well laser structure which has a plurality of quantum well lasers for providing a plurality of light beams each having a different wavelength for use in wavelength division multiplexing.

2 Claims, 3 Drawing Figures